

TECHNICAL DATASHEET

AVNR5500H50

The AVNR5500H50 is a 100W high gain Solid State Narrowband High Power Amplifier. This amplifier module utilizes the latest high power RF GaN transistors and also features built in control and monitoring, with protection functions to ensure high availability. This amplifier is suitable for broadband jamming and EMC testing.

**Features**

- 5GHz-6GHz frequency range
- Psat 50dBm min.
- Power gain 50 dB.
- 50 ohm input/output impedance
- Built-in control, monitoring and protection circuits
- Solid-state Class AB Broadband design
- Instantaneous ultra-broadband
- Suitable for CW, and Pulse
- Small and lightweight
- High reliability and ruggedness

**ELECTRICAL SPECIFICATIONS(T=25°C,DC Voltage= 30V, Load VSWR ≤ 1.2)**

| Description                           | Symbol                           | Min | Typ     | Max     | Unit |
|---------------------------------------|----------------------------------|-----|---------|---------|------|
| Operating Frequency                   | BW                               | 5   |         | 6       | GHz  |
| Output Power CW @ Pin = 0dBm          | Psat                             | 100 | 110     |         | W    |
| Power Gain @ Pin = 0dBm               | Gp                               | 50  | 51      |         | dB   |
| Power Gain Flatness @ Pin = 0dBm      | ΔGp                              |     | ±0.8    | ±1.0    | dB   |
| Input Power for Rated PSAT            | P <sub>IN</sub>                  | -1  | 0       | 1       | dBm  |
| Harmonics @ Pin = 0dBm                | 2 <sup>nd</sup> /3 <sup>rd</sup> |     | -30/-30 | -25/-25 | dBc  |
| Spurious Signals@ Pin = 0dBm          | Spur                             |     |         | -60     | dBc  |
| Input Return Loss                     | S11                              |     | -15     | -10     | dB   |
| Third Order Intercept Point           |                                  |     |         |         |      |
| 2-Tone @ 40dBm/Tone, 100kHz Spacing*  | IP3                              |     | N/A     |         | dBc  |
| Operating Voltage                     | VDC                              | 28  | 30      | 32      | V    |
| Quiescent Current @Enable=+3.3V       | IDQ                              |     | 5.5     |         | A    |
| Current Consumption @Pout=100~110 W   | IDD                              |     | 13      | 15.5    | A    |
| Switching Time @ 1kHz TTL, Pin = 0dBm | TON/TOFF                         |     | 2       | 5       | μs   |

**Note\*:** IP3 or IMD3 data, please contact sales engineer.

**MECHANICAL SPECIFICATIONS**

- Cooling External Heat Sink Needed (Not Supplied)
- Length\* Width\*Height[ mm ] 200\*160\*25
- Weight[ Kg ] 2.5
- RF Connector Input SMA, Female
- RF Connector Output Type N, Female

## ENVIRONMENTAL SPECIFICATIONS (Design to Meet)

|  |     |                  |    |
|--|-----|------------------|----|
| Module Operation Temperature* <sup>1</sup> | -20 | 65* <sup>2</sup> | °C |
| Storage Temperature Range                  | -45 | 85               | °C |
| Relative-Humidity                          |     | 95               | %  |
| Altitude * <sup>3</sup>                    | N/A |                  |    |
| Vibration/Shock * <sup>3</sup>             | N/A |                  |    |

**Notes** \*1: Module Operation Temperature can be extended to -45~85°C, Contact Sales for update.

**Notes** \*2: Should Supply Adequate Heat Dissipation, Enough Fan and Heat-Sink is necessary during the Temp Test.

**Notes** \*3: Altitude /Vibration are designed with considerations, but without tests and experiments.

## LIMITS

|                                     |                                   |     |
|-------------------------------------|-----------------------------------|-----|
| Input RF drive level without damage | $P_{in} \leq 10$                  | dBm |
| Load VSWR @ POUT =50W               | $VSWR \leq 5:1$ [Design To Meet]  | N/A |
| Load VSWR @ POUT =80W               | $VSWR \leq 3:1$ [Design To Meet]  | N/A |
| Thermal Degradation                 | 90°C @ heat-sink [recovery@<60°C] | °C  |

## DC INTERFACE CONNECTOR – [Hybrid D-Sub 7-Pin, Male]

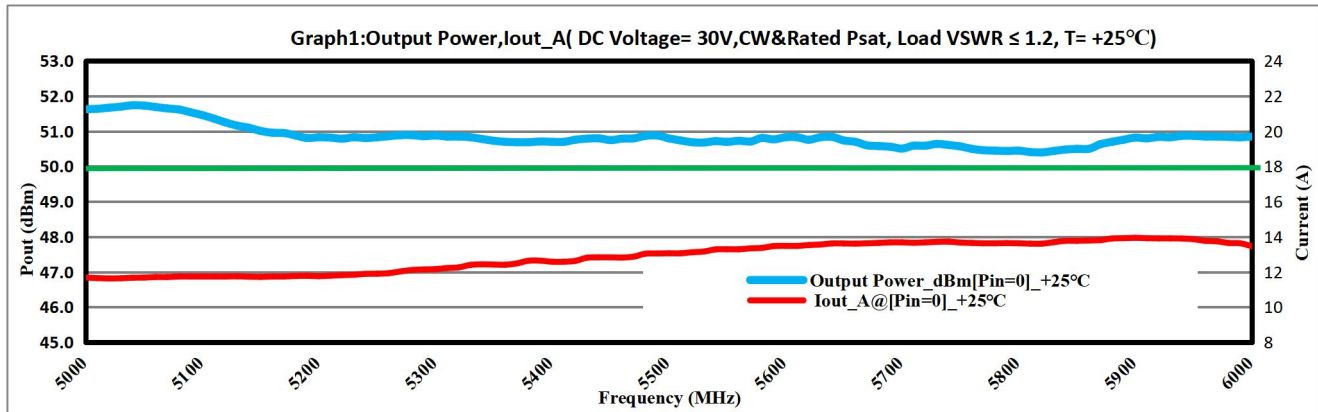
| Pin # | Description     | Specifications  |
|-------|-----------------|---|
| A1    | GND             | Ground  |
| A2    | VDD             | 30VDC   |
| 1     | CURRENT SENSE   | Analog voltage relative to IDD @ 100mV per Ampere                               |
| 2     | TEMP SENSE      | Analog voltage relative to Module's Temperature @ 10 mV/°C                      |
| 3     | ENABLE          | Amplifier Enable: TTL Logic High (3.3V) (Internally Pulled-Low)                 |
| 4     | GND             | Ground  |
| 5     | POWER INDICATOR | Output power $\geq 47 \pm 2$ dBm: TTL Logic High (3.3V) (Internally Pulled-Low) |

## PLOTTED AND OTHER DATA

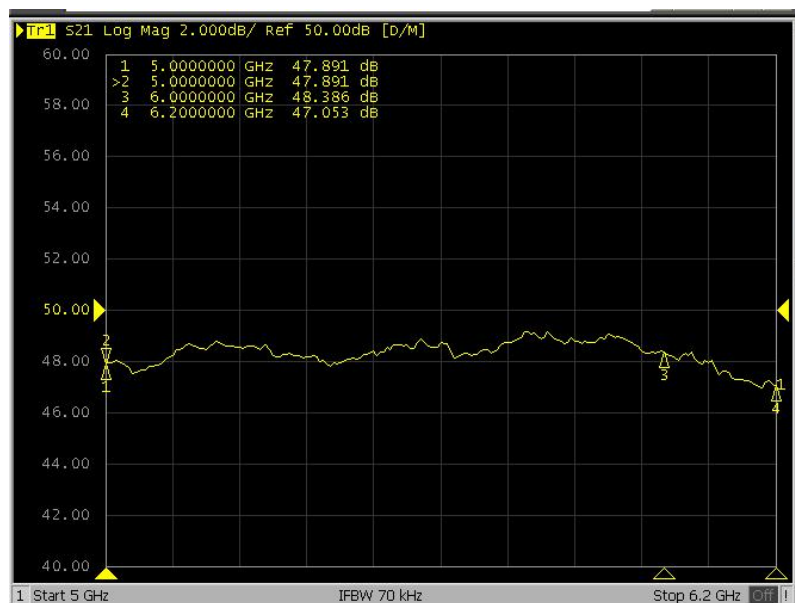
Notes:

1. Values at +25°C, sea level.
2. ESD Sensitive Material, Transport material in Approved ESD bags. Handle only in approved ESD Workstation.
3. Heat Sink required for Proper Operation, Unit is cooled by conduction to heat sink.

TYPICAL PERFORMANCE DATA [Load VSWR ≤ 1.2], (Normal temp. +25±3°C, Heat-Sink with Fan Cooling)



S21, Pin=0dBm, [Load VSWR ≤ 1.2], For Reference Only



OUTLINE DRAWING [mm]

